

APM4115PUC-TRL-VB Datasheet P-Channel 40 V (D-S) MOSFET

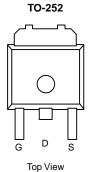
PRODUCT SUMMARY						
V _{DS} (V)	-40					
$R_{DS(on)}(\Omega)$ at V_{GS} = -10 V	0.012					
$R_{DS(on)}$ (Ω) at V_{GS} = -4.5 V	0.015					
I _D (A)	-50					
Configuration	Single					

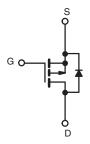
FEATURES

- TrenchFET[®] power MOSFET
- Package with low thermal resistance
- 100 % $\rm R_g$ and UIS tested



FREE





P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS ($T_c = 25 \text{ °C}$, unless otherwise noted)						
PARAMETER	SYMBOL	LIMIT	UNIT			
Drain-Source Voltage	V _{DS}	-40	v			
Gate-Source Voltage	V _{GS}	V _{GS} ± 20				
Continuous Drain Current	T _C = 25 °C a	1	-50			
Continuous Drain Current	T _C = 125 °C	I _D	-39			
Continuous Source Current (Diode Conduction)	a	I _S	-50	A		
Pulsed Drain Current ^b		I _{DM}	-200			
Single Pulse Avalanche Current		I _{AS}	-40			
Single Pulse Avalanche Energy	L = 0.1 mH	E _{AS}	80	mJ		
	T _A = 25 °C		3			
Maximum Power Dissipation ^b	T _C = 25 °C	PD	136	W		
	T _C = 125 °C		45	1		
Operating Junction and Storage Temperature Ra	T _J , T _{stg}	-55 to +175	°C			

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount ^c	R _{thJA}	50	°C/W
Junction-to-Case (Drain)		R _{thJC}	1.1	0/10

Notes

a. Package limited.

b. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

c. When mounted on 1" square PCB (FR4 material).

d. Parametric verification ongoing.

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SYMBOL	1	T CONDITIONS	MIN.	TYP.	MAX.	UNIT	
V _{DS}	V _{GS} =	= 0 V, I _D = -250 μA	-40	-	-	V	
V _{GS(th)}	V _{DS} =	V_{GS} , I_D = -250 μ A	-1.0	-	-3.5	v	
I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$		-	-	± 100	nA	
I _{DSS}	$V_{GS} = 0 V$	V _{DS} = -40 V	-	-	-1		
	$V_{GS} = 0 V$	$V_{DS} = -40 \text{ V}, \text{ T}_{J} = 125 ^{\circ}\text{C}$	-	-	-50	μA	
	$V_{GS} = 0 V$	$V_{DS} = -40 \text{ V}, \text{ T}_{J} = 175 ^{\circ}\text{C}$	-	-	-150		
I _{D(on)}	$V_{GS} = -10 V$	$V_{DS} \le -5 V$	-50	-	-	А	
R _{DS(on)}	V _{GS} = -10 V	I _D = -17 A	-	0.012	-		
	$V_{GS} = -10 \text{ V}$	I _D = -10 A, T _J = 125 °C	-	0.017	-	Ω	
	V _{GS} = -10 V	I _D = -10 A, T _J = 175 °C	-	0.020	-		
	V _{GS} = -4.5 V	I _D = -14 A	-	0.015	-	1	
g _{fs}	V _{DS} =	-15 V, I _D = -17 A	-	61	-	S	
				•	-		
C _{iss}			-	3000	-		
	SYMBOL V _{DS} V _{GS(th)} I _{GSS} I _{DSS} I _{D(on)} R _{DS(on)} gfs	$\begin{tabular}{ c c c c c c } \hline V_{DS} & V_{GS} & V_{GS} & = \\ \hline V_{GS}(th) & V_{DS} & = \\ \hline I_{GSS} & V_{DS} & = \\ \hline I_{DSS} & V_{GS} & = 0 \ V & V_{GS} & = -10 \ V & V_{GS} & = -10$	$\begin{tabular}{ c c c c c } \hline SYMBOL & TEST CONDITIONS \\ \hline V_{DS} & V_{GS} = 0 \ V, \ I_D = -250 \ \mu A \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, \ I_D = -250 \ \mu A \\ \hline I_{GSS} & V_{DS} = 0 \ V, \ V_{GS} = \pm 20 \ V \\ \hline I_{DSS} & V_{GS} = 0 \ V & V_{DS} = -40 \ V, \ T_J = 125 \ ^{\circ}C \\ \hline V_{GS} = 0 \ V & V_{DS} = -40 \ V, \ T_J = 125 \ ^{\circ}C \\ \hline V_{GS} = 0 \ V & V_{DS} = -40 \ V, \ T_J = 175 \ ^{\circ}C \\ \hline I_{D(on)} & V_{GS} = -10 \ V & V_{DS} = -40 \ V, \ T_J = 125 \ ^{\circ}C \\ \hline V_{GS} = -10 \ V & I_D = -17 \ A \\ \hline V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 125 \ ^{\circ}C \\ \hline V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 175 \ ^{\circ}C \\ \hline V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 175 \ ^{\circ}C \\ \hline V_{GS} = -45 \ V & I_D = -10 \ A, \ T_J = 175 \ ^{\circ}C \\ \hline V_{GS} = -45 \ V & I_D = -17 \ A \\ \hline \end{tabular}$	$\begin{array}{ c c c c c c } SYMBOL & TEST CONDITIONS & MIN. \\ \hline \\ & V_{DS} & V_{GS} = 0 \ V, \ I_D = -250 \ \mu A & -40 \\ \hline \\ V_{GS(th)} & V_{DS} = V_{GS}, \ I_D = -250 \ \mu A & -1.0 \\ \hline \\ & I_{GSS} & V_{DS} = 0 \ V, \ V_{GS} = \pm 20 \ V & - \\ \hline \\ & V_{GS} = 0 \ V & V_{DS} = -40 \ V & - \\ \hline \\ & V_{GS} = 0 \ V & V_{DS} = -40 \ V, \ T_J = 125 \ ^{\circ}C & - \\ \hline \\ & V_{GS} = 0 \ V & V_{DS} = -40 \ V, \ T_J = 175 \ ^{\circ}C & - \\ \hline \\ & I_{D(on)} & V_{GS} = -10 \ V & V_{DS} = -40 \ V, \ T_J = 175 \ ^{\circ}C & - \\ \hline \\ & V_{GS} = -10 \ V & I_D = -17 \ A & - \\ \hline \\ & V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 125 \ ^{\circ}C & - \\ \hline \\ & V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 175 \ ^{\circ}C & - \\ \hline \\ & V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 175 \ ^{\circ}C & - \\ \hline \\ & V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 175 \ ^{\circ}C & - \\ \hline \\ & V_{GS} = -10 \ V & I_D = -10 \ A, \ T_J = 175 \ ^{\circ}C & - \\ \hline \\ & V_{GS} = -15 \ V, \ I_D = -17 \ A & - \\ \hline \end{array}$	$\begin{tabular}{ c c c c c c c } \hline SYMBOL & TEST CONDITIONS & MIN. & TYP. \\ \hline SYMBOL & V_{GS} = 0 V, I_D = -250 \ \mu A & -40 & - \\ \hline V_{GS(th)} & V_{DS} = V_{GS}, I_D = -250 \ \mu A & -1.0 & - \\ \hline V_{GS} & V_{DS} = 0 V, V_{GS} = \pm 20 \ V & - & - \\ \hline I_{GSS} & V_{DS} = 0 V, V_{GS} = \pm 20 \ V & - & - \\ \hline V_{GS} = 0 V & V_{DS} = -40 \ V, T_J = 125 \ ^{\circ}C & - & - \\ \hline V_{GS} = 0 V & V_{DS} = -40 \ V, T_J = 125 \ ^{\circ}C & - & - \\ \hline V_{GS} = 0 V & V_{DS} = -40 \ V, T_J = 175 \ ^{\circ}C & - & - \\ \hline I_{D(on)} & V_{GS} = -10 \ V & I_D = -10 \ A, T_J = 175 \ ^{\circ}C & - & 0.012 \\ \hline V_{GS} = -10 \ V & I_D = -10 \ A, T_J = 175 \ ^{\circ}C & - & 0.020 \\ \hline V_{GS} = -10 \ V & I_D = -10 \ A, T_J = 175 \ ^{\circ}C & - & 0.020 \\ \hline V_{GS} = -40 \ V, I_D = -17 \ A & - & 0.015 \\ \hline g_{fs} & V_{DS} = -45 \ V, I_D = -17 \ A & - & 61 \\ \hline \end{tabular}$	www.VBsc symbol TEST CONDITIONS MIN. TYP. MAX. V_{DS} $V_{GS} = 0 V$, $I_D = -250 \mu A$ -40 $ V_{GS(th)}$ $V_{DS} = V_{GS}$, $I_D = -250 \mu A$ -10 $ -3.5$ I_{GSS} $V_{DS} = 0 V$, $V_{GS} = \pm 20 V$ $ \pm 100$ I_{GSS} $V_{DS} = 0 V$ $V_{DS} = -40 V$ $ -1$ I_{DSS} $V_{GS} = 0 V$ $V_{DS} = -40 V$ $ -100$ I_{DSS} $V_{GS} = 0 V$ $V_{DS} = -40 V$, $T_J = 125 °C$ $ -150$ $I_{D(on)}$ $V_{GS} = -10 V$ $V_{DS} \le -5 V$ -50 $ R_{DS(on)}$ $V_{GS} = -10 V$ $I_D = -17 A$ $ 0.012$ $ V_{GS} = -10 V$ $I_D = -10 A, T_J = 125 °C$ $ 0.012$ $ V_{GS} = -10 V$ $I_D = -10 A, T_J = 175 °C$ $ 0.020$ $ g_{fs}$ <	

Dynamic ^b							
Input Capacitance	C _{iss}			-	3000	-	
Output Capacitance	C _{oss}	$V_{GS} = 0 V$	V _{DS} = -25 V, f = 1 MHz	-	508	635	pF
Reverse Transfer Capacitance	C _{rss}			-	352	440	
Total Gate Charge ^c	Qg		V _{DS} = -30 V, I _D = -50 A	-	60	80	nC
Gate-Source Charge ^c	Q _{gs}	$V_{GS} = -10 \text{ V}$		-	5.7	8.6	
Gate-Drain Charge ^c	Q _{gd}			-	14.7	22	
Gate Resistance	R _g	f = 1 MHz		1.5	3	4.5	Ω
Turn-On Delay Time ^c	t _{d(on)}			-	10	15	
Rise Time ^c	t _r	V _{DD} =	$V_{DD} = -20 \text{ V}, \text{ R}_{\text{I}} = 0.4 \Omega$		12	18	
Turn-Off Delay Time ^c	t _{d(off)}	$I_D \cong -50 \text{ A}, V_{\text{GEN}} = -10 \text{V}, \text{R}_{\text{g}} = 1 \Omega$		-	40	60	ns
Fall Time ^c	t _f			-	16	24	
Source-Drain Diode Ratings and Characteristics ^b							
Pulsed Current ^a	I _{SM}			-	-	-200	А
Forward Voltage	V _{SD}	I _F = -50 A, V _{GS} = 0 V		-	-1	-1.5	V

Notes

a. Pulse test; pulse width $\leq 300~\mu\text{s},~\text{duty}~\text{cycle} \leq 2~\%.$

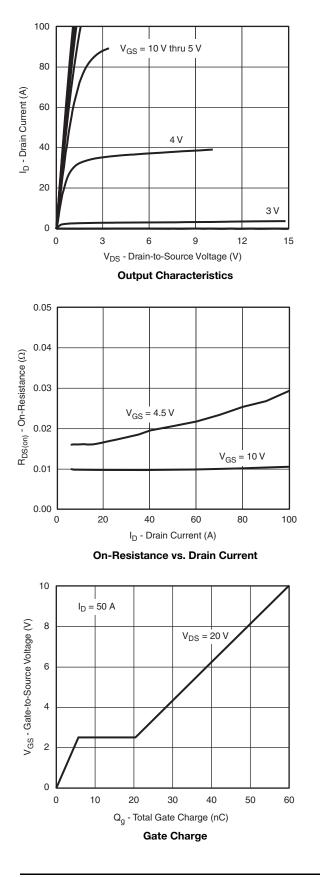
b. Guaranteed by design, not subject to production testing.

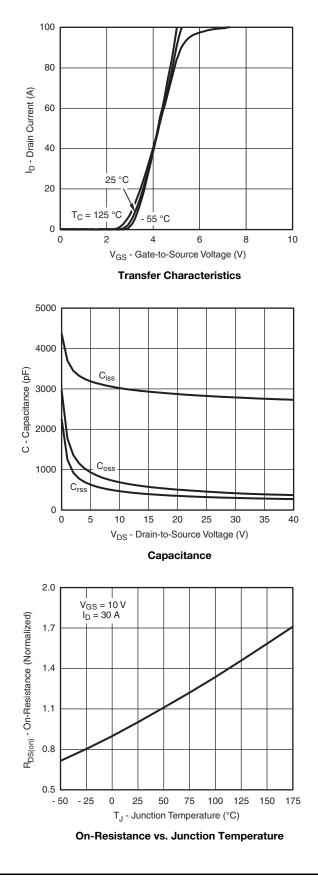
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



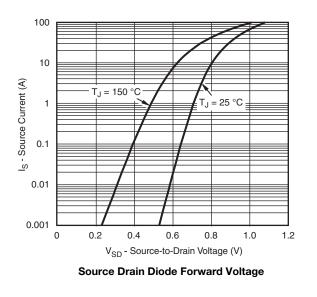
TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)

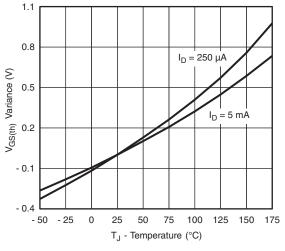




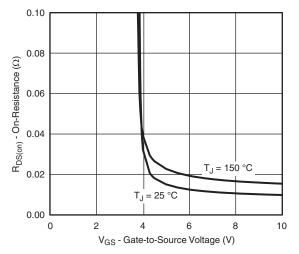


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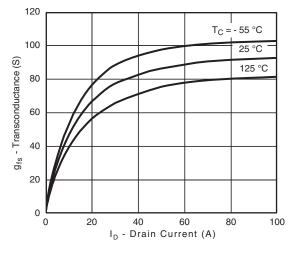




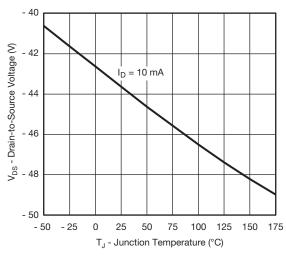


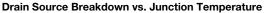


On-Resistance vs. Gate-to Source Voltage



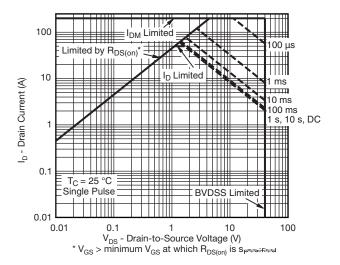




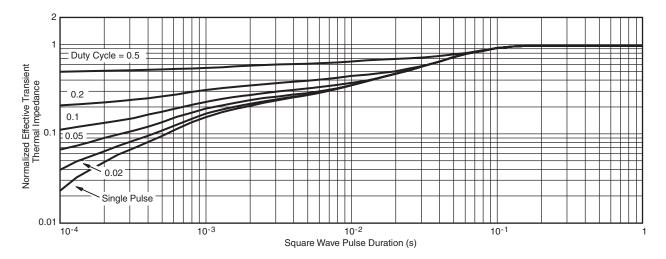




TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)

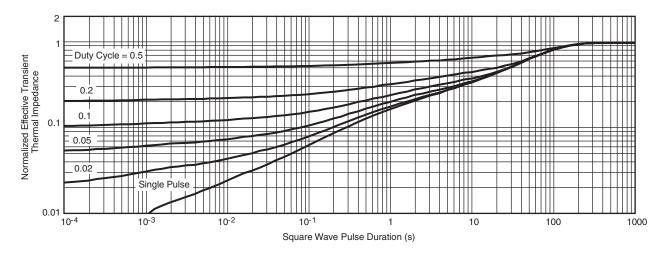


Safe Operating Area



Normalized Thermal Transient Impedance, Junction-to-Case





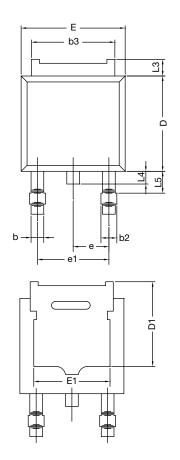
Normalized Thermal Transient Impedance, Junction-to-Ambient

Note

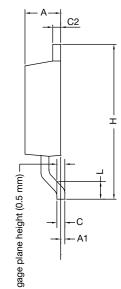
- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.





TO-252AA Case Outline



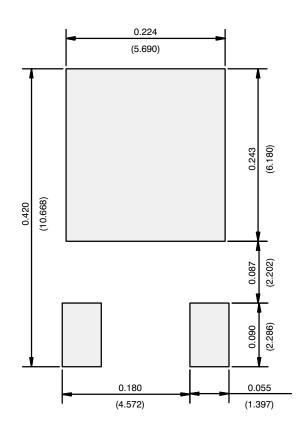
	MILLIN	IETERS	INCHES		
DIM.	MIN.	MAX.	MIN.	MAX.	
А	2.18	2.38	0.086	0.094	
A1	-	0.127	-	0.005	
b	0.64	0.88	0.025	0.035	
b2	0.76	1.14	0.030	0.045	
b3	4.95	5.46	0.195	0.215	
С	0.46	0.61	0.018	0.024	
C2	0.46	0.89	0.018	0.035	
D	5.97	6.22	0.235	0.245	
D1	4.10	-	0.161	-	
Е	6.35	6.73	0.250	0.265	
E1	4.32	-	0.170	-	
Н	9.40	10.41	0.370	0.410	
е	2.28	BSC	0.090	BSC	
e1	4.56	4.56 BSC		BSC	
L	1.40	1.78	0.055	0.070	
L3	0.89	1.27	0.035	0.050	
L4	-	1.02	-	0.040	
L5	1.01	1.52	0.040	0.060	
ECN: T13-0592-Rev. A, 02-Sep-13 DWG: 6019					

Note

• Dimension L3 is for reference only.



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)



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